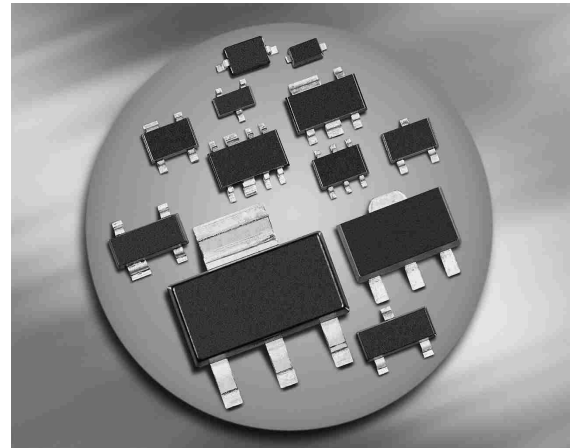


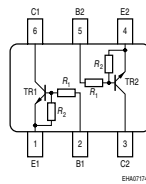
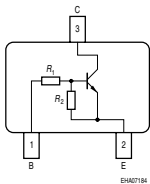
NPN Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ($R_1=2.2k\Omega$, $R_2=47k\Omega$)
- For 6-PIN packages: two (galvanic) internal isolated transistors with good matching in one package



BCR108/F/L3
BCR108T/W

BCR108S
SEMH10



Type	Marking	Pin Configuration						Package
BCR108	WHs	1=B	2=E	3=C	-	-	-	SOT23
BCR108F	WHs	1=B	2=E	3=C	-	-	-	TSFP-3
BCR108L3	WH	1=B	2=E	3=C	-	-	-	TSLP-3-4
BCR108S	WHs	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SOT363
BCR108T	WHs	1=B	2=E	3=C	-	-	-	SC75
BCR108W	WHs	1=B	2=E	3=C	-	-	-	SOT323
SEMH10	WH	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SOT666

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Emitter-base voltage	V_{EBO}	5	
Input on voltage	$V_{I(on)}$	10	
Collector current	I_C	100	mA
Total power dissipation- BCR108, $T_S \leq 102^\circ\text{C}$ BCR108F, $T_S \leq 128^\circ\text{C}$ BCR108L3, $T_S \leq 135^\circ\text{C}$ BCR108S, $T_S \leq 115^\circ\text{C}$ BCR108T, $T_S \leq 109^\circ\text{C}$ BCR108W, $T_S \leq 124^\circ\text{C}$ SEMH10, $T_S \leq 75^\circ\text{C}$	P_{tot}	200 250 250 250 250 250 250	mW
Junction temperature	T_j	150	
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R_{thJS}		K/W
BCR108		≤ 240	
BCR108F		≤ 90	
BCR108L3		≤ 60	
BCR108S		≤ 140	
BCR108T		≤ 165	
BCR108W		≤ 105	
SEMH10		≤ 300	

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

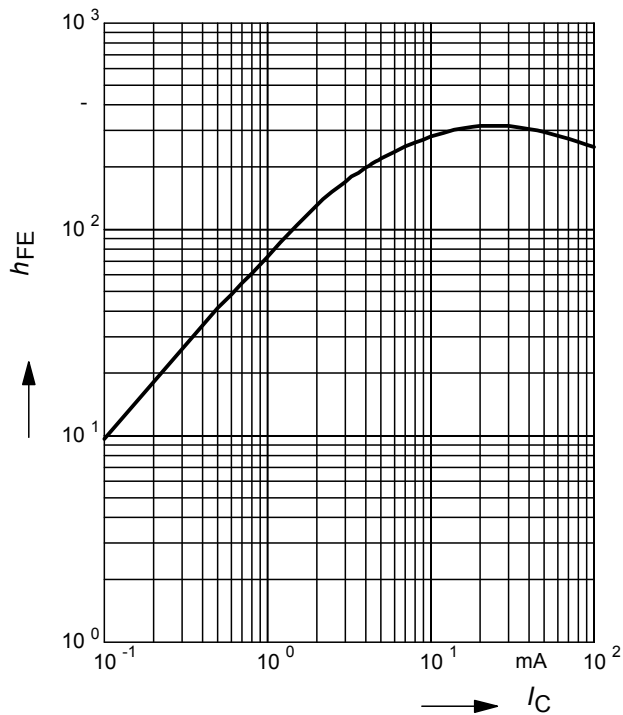
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage $I_C = 100\ \mu\text{A}$, $I_B = 0$	$V_{(\text{BR})\text{CEO}}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10\ \mu\text{A}$, $I_E = 0$	$V_{(\text{BR})\text{CBO}}$	50	-	-	
Collector-base cutoff current $V_{\text{CB}} = 40\ \text{V}$, $I_E = 0$	I_{CBO}	-	-	100	nA
Emitter-base cutoff current $V_{\text{EB}} = 5\ \text{V}$, $I_C = 0$	I_{EBO}	-	-	164	μA
DC current gain ¹⁾ $I_C = 5\ \text{mA}$, $V_{\text{CE}} = 5\ \text{V}$	h_{FE}	70	-	-	-
Collector-emitter saturation voltage ¹⁾ $I_C = 10\ \text{mA}$, $I_B = 0.5\ \text{mA}$	V_{CEsat}	-	-	0.3	V
Input off voltage $I_C = 100\ \mu\text{A}$, $V_{\text{CE}} = 5\ \text{V}$	$V_{\text{i(off)}}$	0.4	-	0.8	
Input on voltage $I_C = 2\ \text{mA}$, $V_{\text{CE}} = 0.3\ \text{V}$	$V_{\text{i(on)}}$	0.5	-	1.1	
Input resistor	R_1	1.5	2.2	2.9	k Ω
Resistor ratio	R_1/R_2	0.042	0.047	0.052	-
AC Characteristics					
Transition frequency $I_C = 10\ \text{mA}$, $V_{\text{CE}} = 5\ \text{V}$, $f = 1\ \text{MHz}$	f_{T}	-	170	-	MHz
Collector-base capacitance $V_{\text{CB}} = 10\ \text{V}$, $f = 1\ \text{MHz}$	C_{cb}	-	2	-	pF

¹⁾Pulse test: $t < 300\ \mu\text{s}$; $D < 2\%$

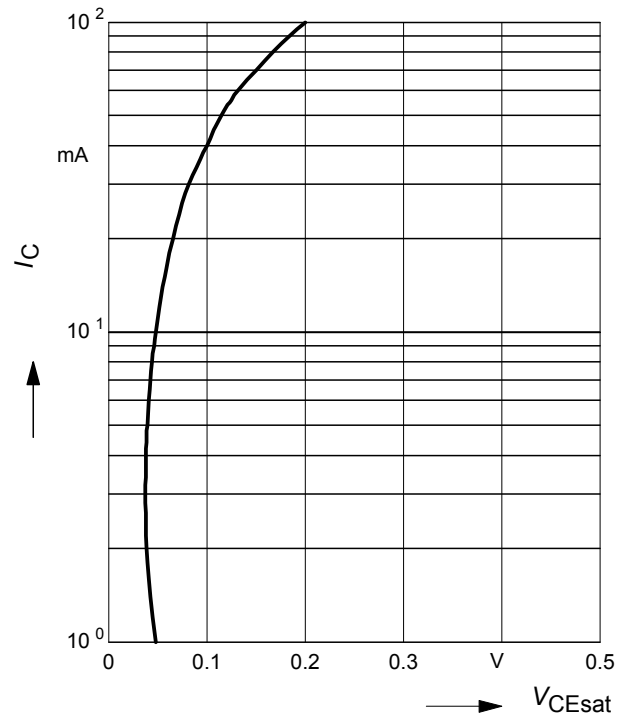
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



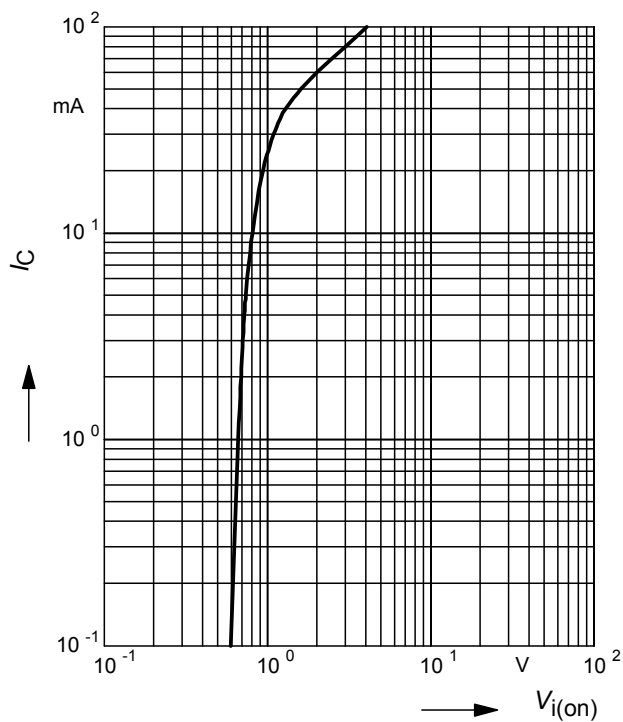
Collector-emitter saturation voltage

$V_{CEsat} = f(I_C), h_{FE} = 20$



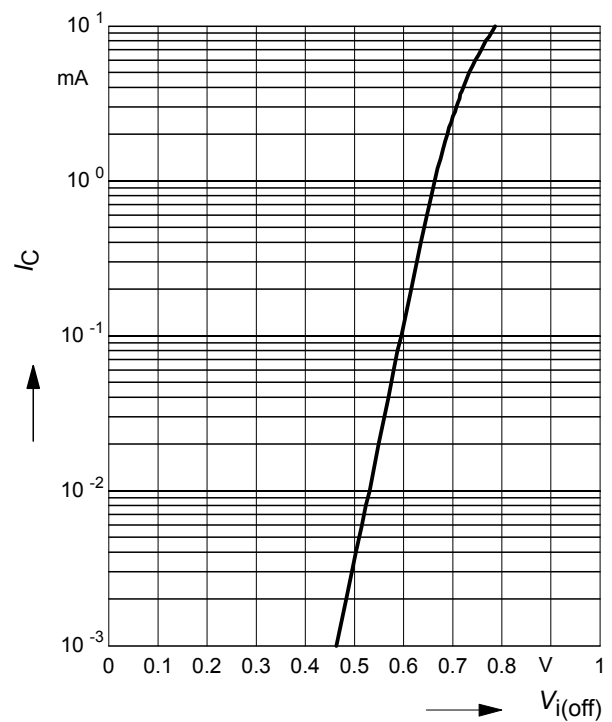
Input on Voltage $V_{i(on)} = f(I_C)$

$V_{CE} = 0.3V$ (common emitter configuration)



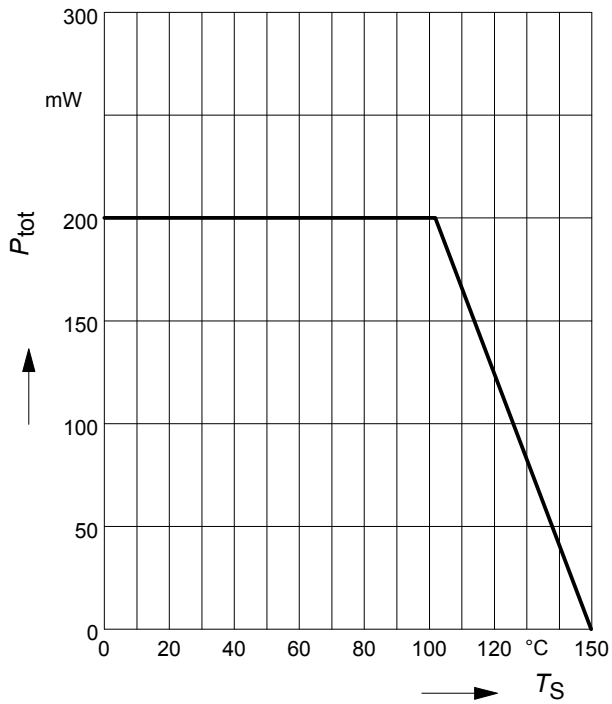
Input off voltage $V_{i(off)} = f(I_C)$

$V_{CE} = 5V$ (common emitter configuration)



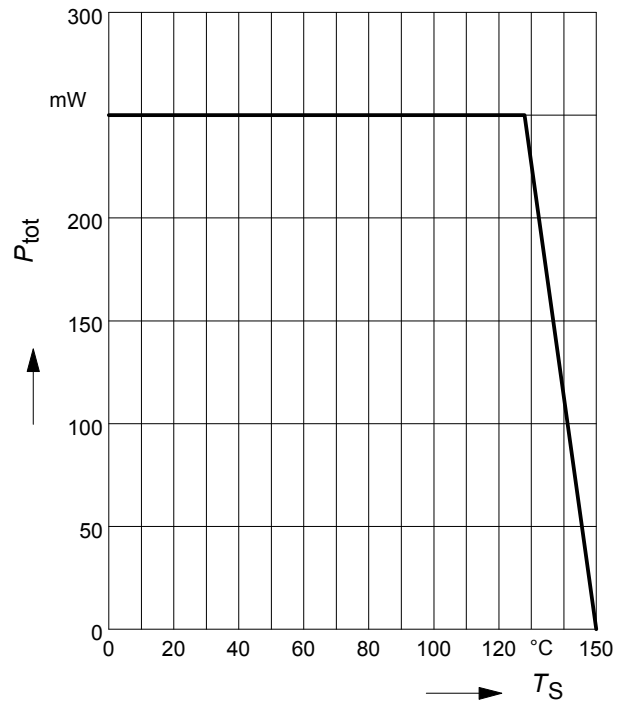
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR108



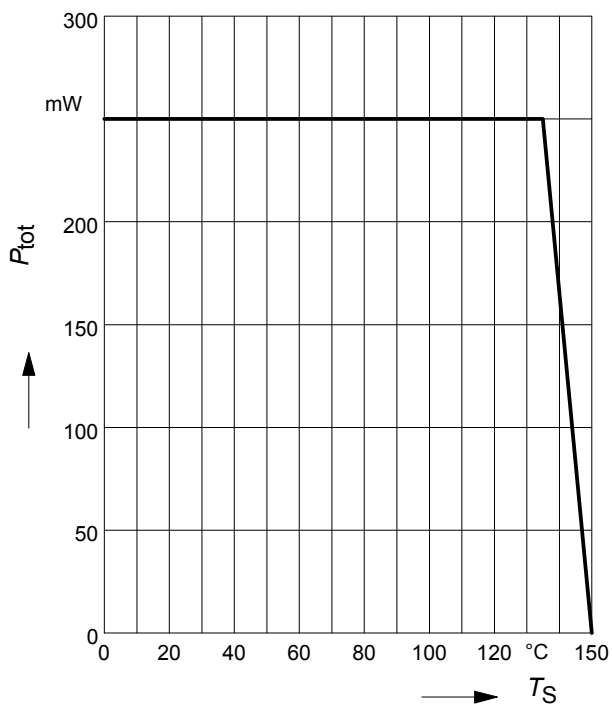
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR108F



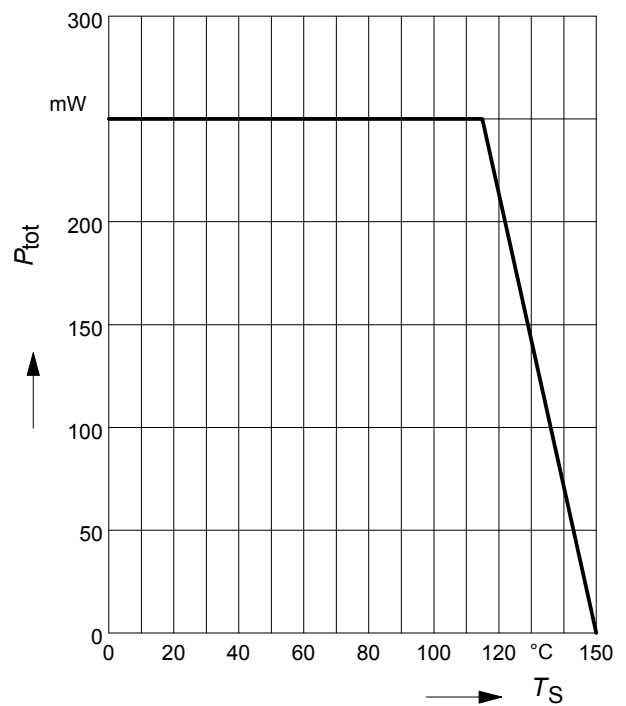
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR108L3



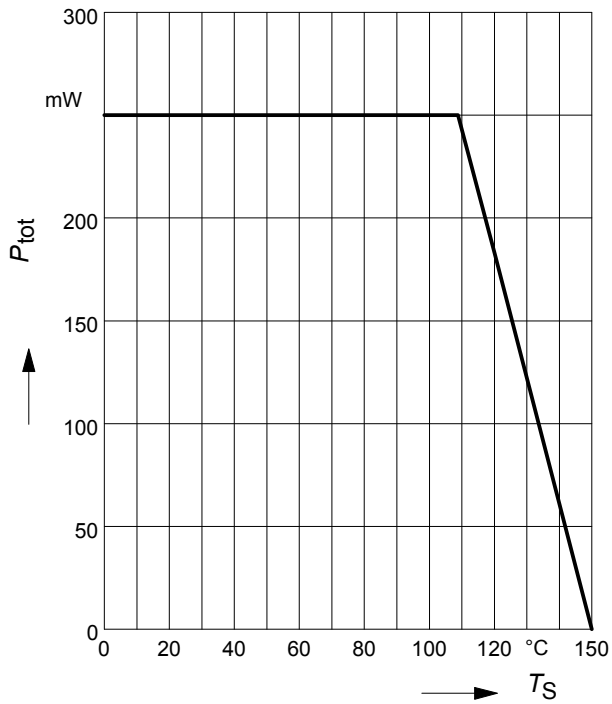
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR108S



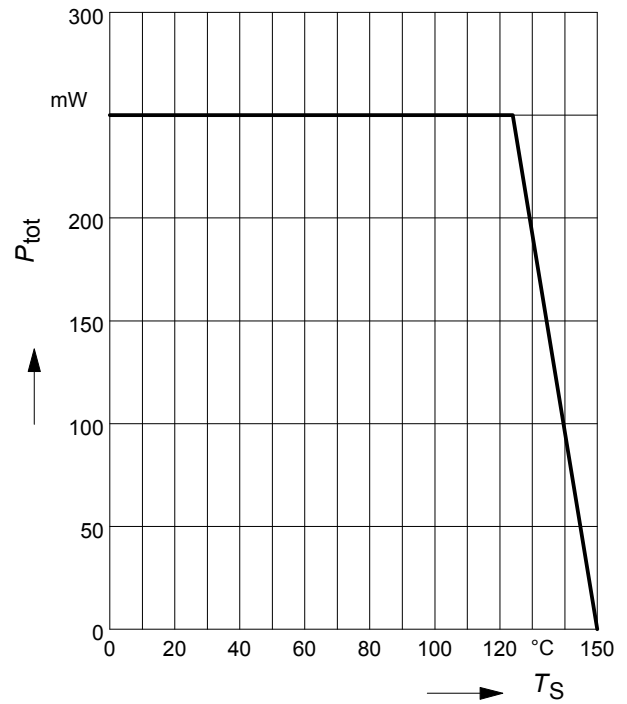
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR108T



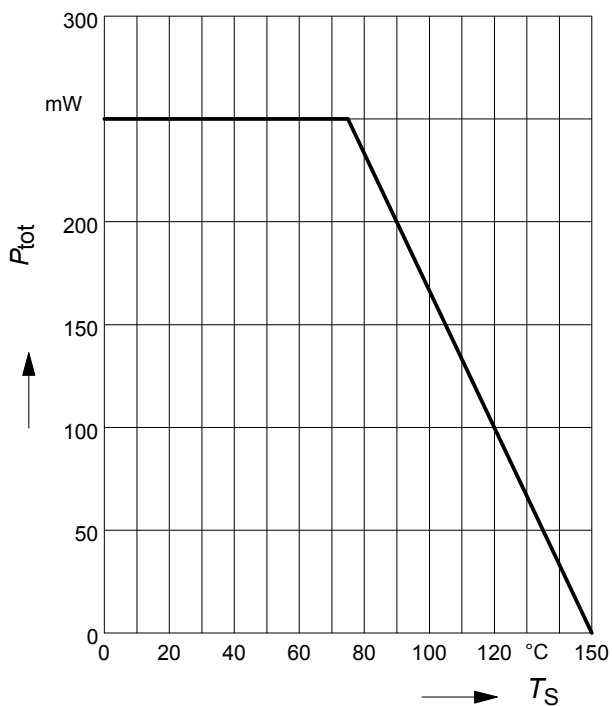
Total power dissipation $P_{\text{tot}} = f(T_S)$

BCR108W



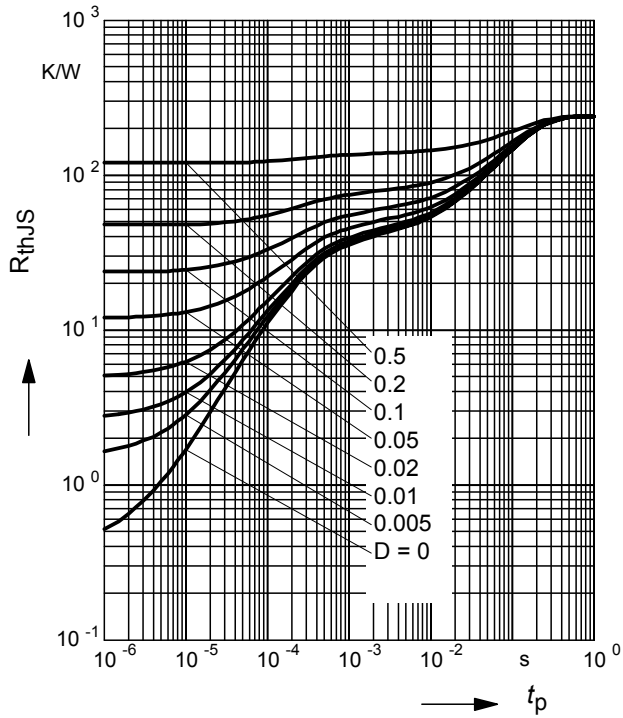
Total power dissipation $P_{\text{tot}} = f(T_S)$

SEMH10



Permissible Pulse Load $R_{thJS} = f(t_p)$

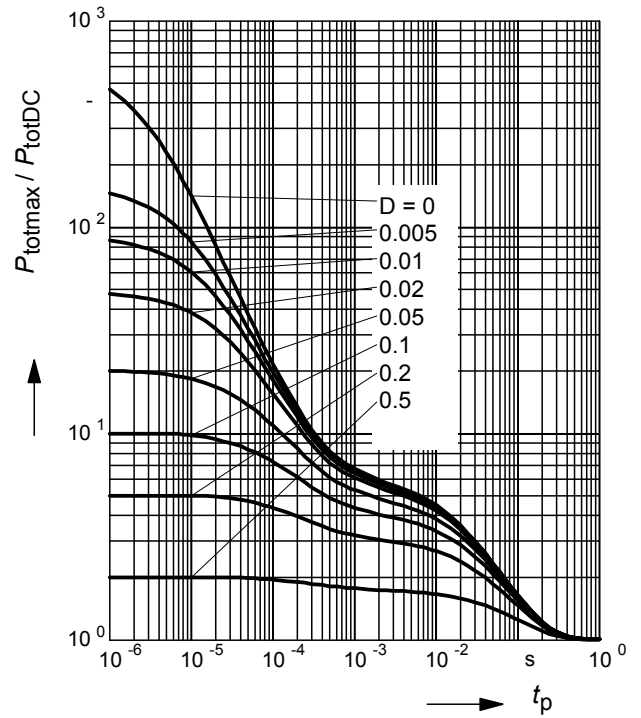
BCR108



Permissible Pulse Load

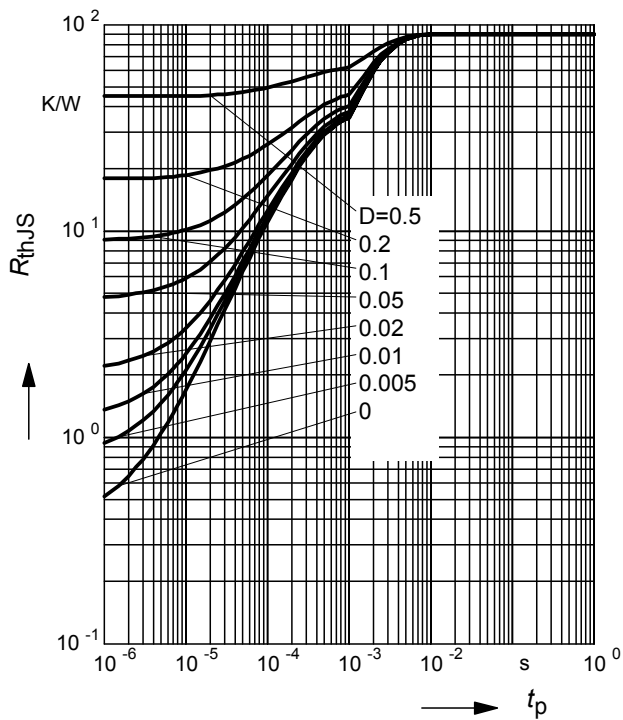
$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR108



Permissible Puls Load $R_{thJS} = f(t_p)$

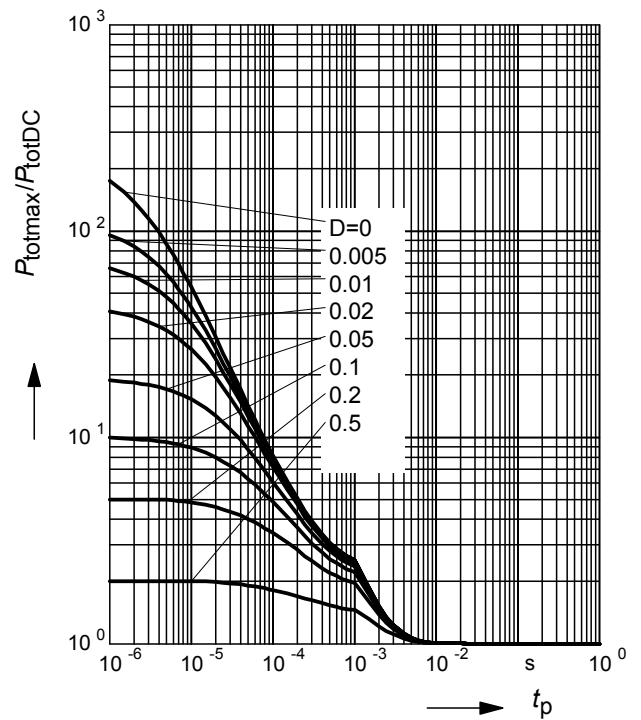
BCR108F



Permissible Pulse Load

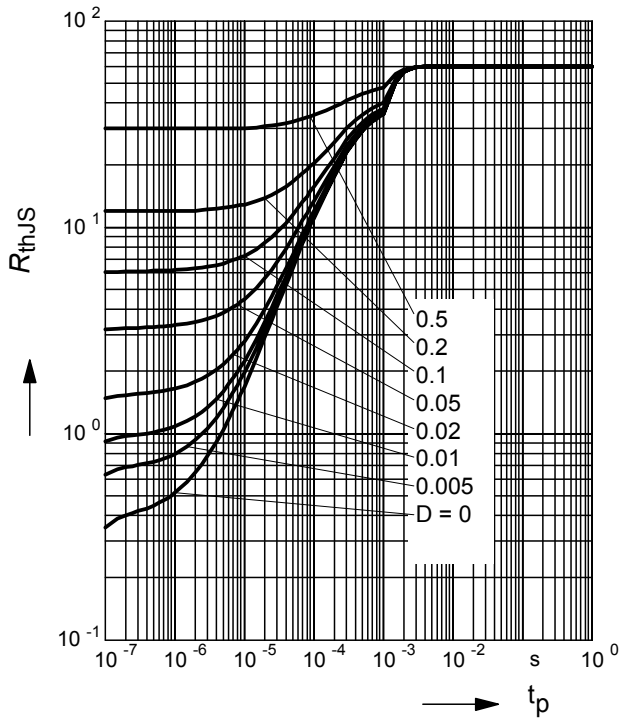
$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR108F



Permissible Puls Load $R_{thJS} = f(t_p)$

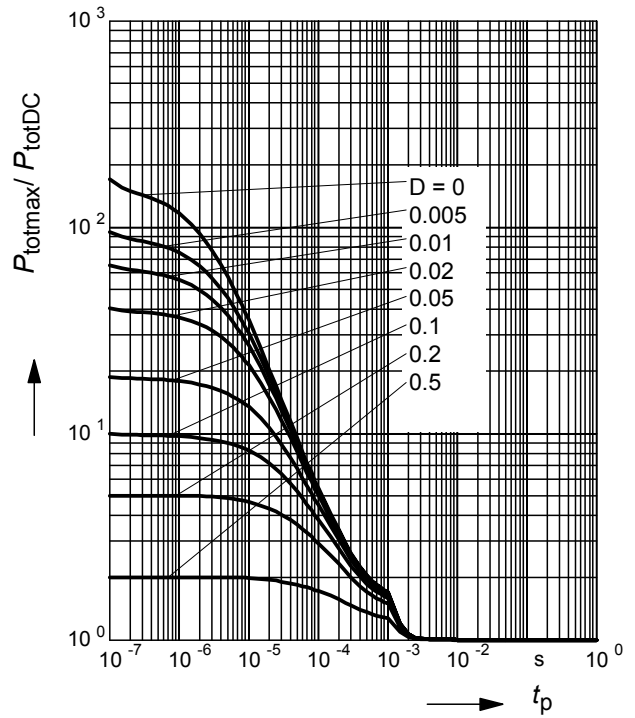
BCR108L3



Permissible Pulse Load

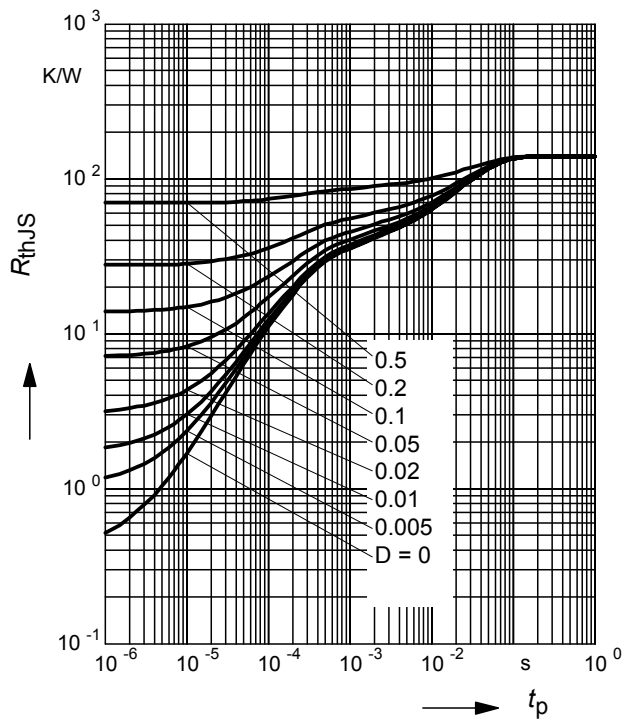
$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR108L3



Permissible Puls Load $R_{thJS} = f(t_p)$

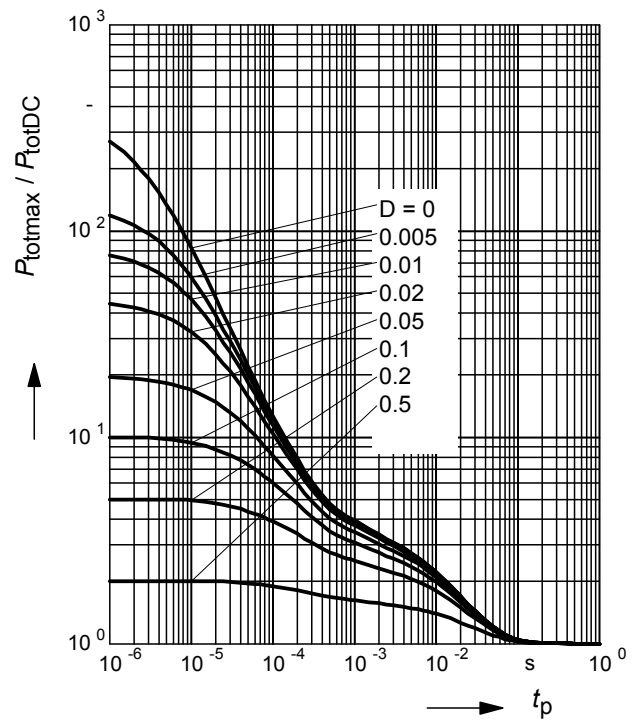
BCR108S



Permissible Pulse Load

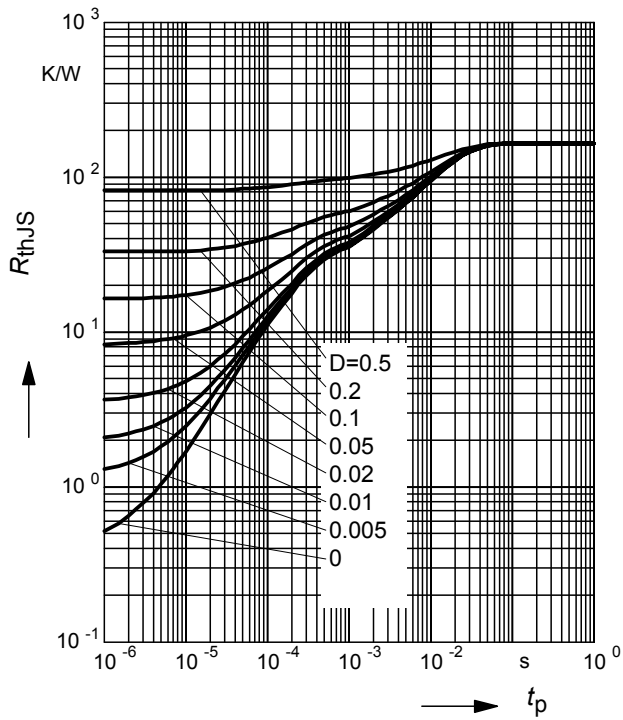
$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR108S



Permissible Puls Load $R_{thJS} = f(t_p)$

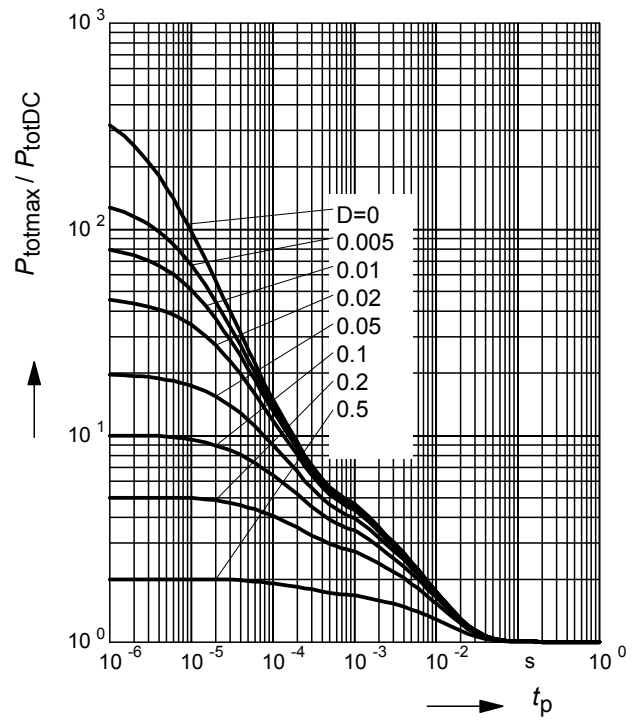
BCR108T



Permissible Pulse Load

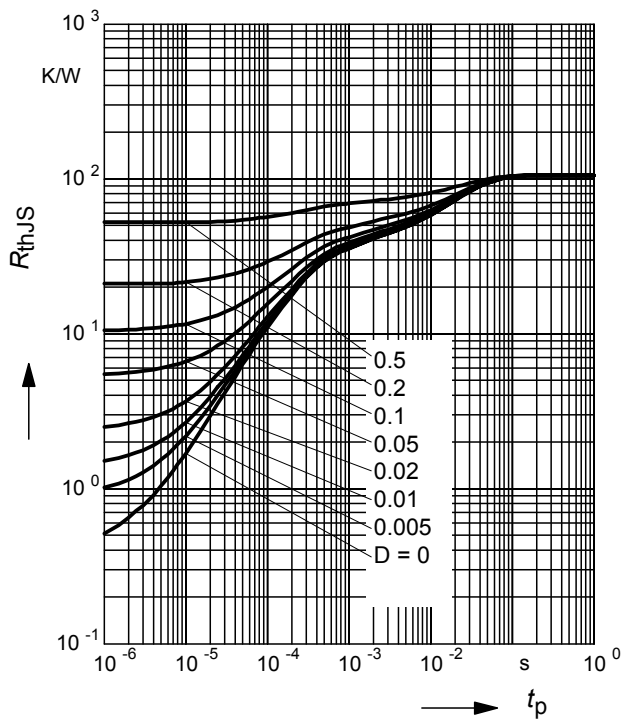
$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR108T



Permissible Puls Load $R_{thJS} = f(t_p)$

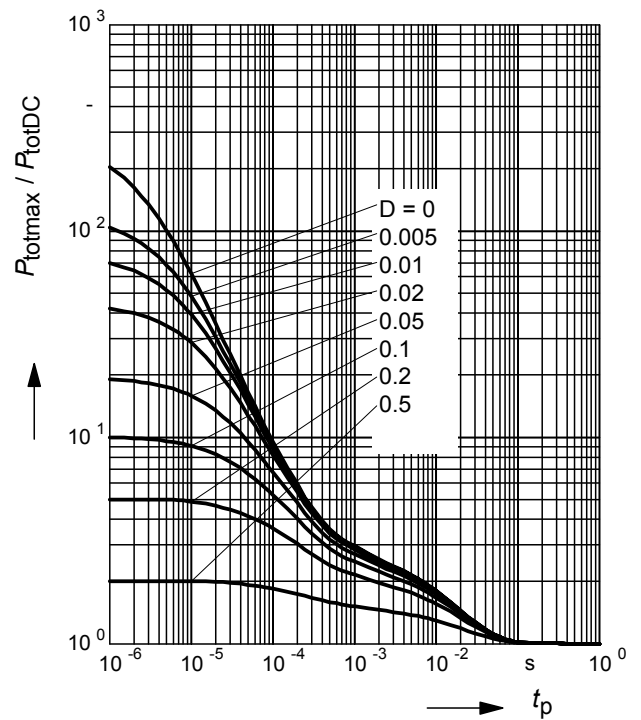
BCR108W



Permissible Pulse Load

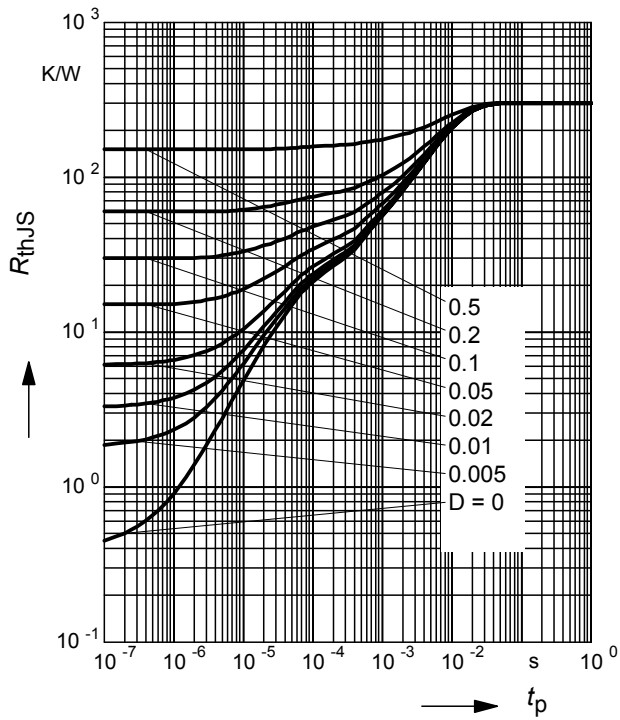
$$P_{totmax}/P_{totDC} = f(t_p)$$

BCR108W



Permissible Puls Load $R_{thJS} = f(t_p)$

SEMH10



Permissible Pulse Load

$$P_{totmax}/P_{totDC} = f(t_p)$$

SEMH10

